



#### **DUAL N-CHANNEL ENHANCEMENT MODE MOSFET**

#### **Features**

- **Dual N-Channel MOSFET**
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q101, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotive-

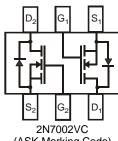
- This part is qualified to JEDEC standards (as references in AEC-Q101) for High Reliability.
- https://www.diodes.com/quality/product-definitions/

#### **Mechanical Data**

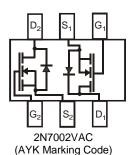
- Case: SOT563
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram (Note 3)
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.003 grams (approximate)







(ASK Marking Code)



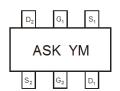
#### **Ordering Information** (Note 4)

Part Number	Case	Packaging
2N7002VC-7	SOT563	3000/Tape & Reel
2N7002VAC-7	SOT563	3000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

## Marking Information



ASK = 2N7002VC Product Type Marking Code YM = Date Code Marking Y = Year ex: R = 2004

M = Month ex: 9 = September



AYK = 2N7002VAC Product Type Marking Code YM = Date Code Marking Y = Year ex: R = 2004 M = Month ex: 9 = September

#### Date Code Kev

Year	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014	2015	2016	2017
Code	R	S	Т	U	V	W	Х	Υ	Z	Α	В	С	D	Е
Month	Jan	Feb	Ма	ar .	Apr	May	Jun	Jul	Aug	Se	p (	Oct	Nov	Dec
Code	1	2	3		4	5	6	7	8	9		0	N	D



## **Maximum Ratings** @T<sub>A</sub> = +25°C unless otherwise specified

Characteristic		Symbol	Value	Units
Drain-Source Voltage		$V_{DSS}$	60	V
Drain-Gate Voltage R <sub>GS</sub> ≤ 1.0MΩ		$V_{DGR}$	60	V
Gate-Source Voltage (Note 5)	Continuous Pulsed	$V_{GSS}$	±20 ±40	V
Drain Current (Note 5)	Continuous	I <sub>D</sub>	280	mA
Drain Current (Note 5)	Pulsed	I <sub>DM</sub>	1.5	A

### Thermal Characteristics @TA = +25°C unless otherwise specified

Characteristic	Symbol	Value	Units
Total Power Dissipation	$P_{D}$	150	mW
Thermal Resistance, Junction to Ambient	$R_{ hetaJA}$	833	°C/W
Operating and Storage Temperature Range	$T_{J_1}T_{STG}$	-55 to +150	°C

### Electrical Characteristics @TA = +25°C unless otherwise specified

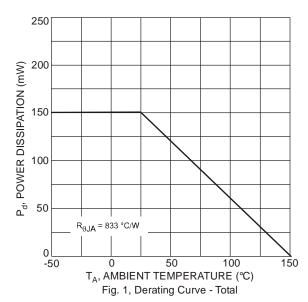
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	70	_	V	$V_{GS} = 0V, I_{D} = 10\mu A$	
Zero Gate Voltage Drain Current $@T_C = +2$ $@T_C = +12$	Inco	_	_	1.0 500	μΑ	$V_{DS} = 60V, V_{GS} = 0V$	
Gate-Body Leakage	I <sub>GSS</sub>			±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTIC (Note 6)							
Gate Threshold Voltage	$V_{GS(th)}$	1.0	_	2.5	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance	R <sub>DS</sub> (ON)			7.5 13.5	Ω	$V_{GS} = 5V$ , $I_D = 0.05A$ , $V_{GS} = 10V$ , $I_D = 0.5A$ , $T_i = 125$ °C	
On-State Drain Current	I <sub>D(ON)</sub>	0.5	1.0	_	Α	V <sub>GS</sub> = 10V, V <sub>DS</sub> = 7.5V	
Forward Transconductance	g <sub>FS</sub>	80	_	_	mS	$V_{DS} = 10V, I_D = 0.2A$	
DYNAMIC CHARACTERISTICS							
Input Capacitance	C <sub>iss</sub>	_	_	50	рF		
Output Capacitance		_	_	25	pF	$V_{DS} = 25V$ , $V_{GS} = 0V$ , $f = 1.0MHz$	
Reverse Transfer Capacitance	C <sub>rss</sub>	_	_	5.0	рF		
SWITCHING CHARACTERISTICS							
Turn-On Delay Time	t <sub>D(ON)</sub>	_	_	20	ns	$V_{DD} = 30V, I_D = 0.2A, R_L = 150\Omega,$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	_	20	ns	$V_{GEN} = 10V$ , $R_{GEN} = 25\Omega$	

Notes:

<sup>5.</sup> Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com.

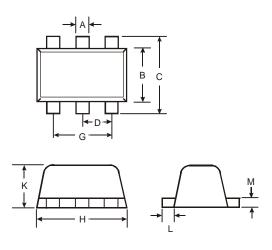
<sup>6.</sup> Short duration pulse test used to minimize self-heating effect.





# **Package Outline Dimensions**

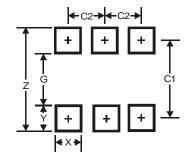
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT563							
Dim	Min	Max	Тур				
Α	0.15	0.30	0.20				
В	1.10	1.25	1.20				
С	1.55	1.70	1.60				
D	-	-	0.50				
G	0.90	1.10	1.00				
Н	1.50	1.70	1.60				
K	0.55	0.60	0.60				
L	0.10	0.30	0.20				
M	0.10	0.18	0.11				
All Dimensions in mm							

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
Z	2.2
G	1.2
Х	0.375
Y	0.5
C1	1.7
C2	0.5



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